Phase-field study of surface diffusion enhanced break-ups of nanowire junctions

Abhinav Roy\textsuperscript{1}, Arjun Varma R.\textsuperscript{2}, and M. P. Gururajan\textsuperscript{2}
\textsuperscript{1} Department of Metallurgical and Materials Engineering, National Institute of Technology Rourkela, Odisha, 769008 INDIA
\textsuperscript{2} Department of Metallurgical Engineering and Materials Science, Indian Institute of Technology Bombay, Powai, Mumbai, Maharashtra, 400076 INDIA
E-mail: guru.mp@iitb.ac.in, gururajan.mp@gmail.com

Abstract. Using a phase-field model which incorporates enhanced diffusion at the nanowire surfaces, we study the effect of different parameters on the stability of intersecting nanowires. Our study shows that at the intersection of nanowires, sintering (curvature driven material flow) leads to the formation of junctions. These junctions act the initiators of nanowire break-up. The subsequent break-ups take place due to Rayleigh instability at the arms away from these junctions. Finally, at long time scales, the fragments coarsen due to the differences in sizes. The radii of the nanowires that form the junction, the difference in size of the intersecting nanowires and the angle of intersection play a dominant role in determining the kinetics of break-up while the density of intersections has little or no effect on the kinetics. The surface energy anisotropy makes the nanowires with favourable interfaces stable. However, even in the case of nanowires with anisotropic interfacial energy, the fragmentation behaviour is qualitatively the same in terms of formation of junctions and the first break-up at the junction. Finally, we rationalise our results using maps of Gaussian curvatures (and, hence chemical potentials).

Keywords: Phase-field modelling, Nanowire sintering, Nanowire junction break-up, Rayleigh instability, Variable mobility, Surface diffusion, Surface energy anisotropy
1. Introduction

Metallic nanowires are used in a wide range of applications: for example, their ductility and bendability allows for their use in solar cells, flexible and transparent electronic devices, light emitting diodes, and so on – see, for example, [1, 2, 3, 4]. Regular ordered array of metallic nanodots have been used in biosensing applications [5]. In particular, network of Ag nanowires are considered as the next generation of transparent conducting electrodes due to their enhanced electrical and optical properties [6, 7]. Given such widespread use, their stability at elevated temperatures under standard operating conditions is an important area of study. Thus, an understanding of the driving forces for morphological changes and control of the parameters which affect those driving forces are of significant academic and technological importance.

The effect of nanowire size, network density and temperature on the stability of metallic nanowires have been investigated experimentally [8, 9, 10]. The structural stability of the metallic nanowires at the nanoscale is governed by numerous factors — the most dominant factors being Rayleigh instability [11, 12, 13] and anisotropy in interfacial energy [14, 15, 16, 17, 18]. Thermally accelerated surface diffusion plays a central role in the resulting change in morphology of the metallic nanowires due to Rayleigh instability, and their subsequent break-up into nanodots [19, 20, 21, 22, 23, 24, 25]. Rayleigh instability mediated nanowire fragmentation has also been observed in non-metallic nanowires [26, 27]. Quantum effects at the nanoscale also play a role in morphological evolution in conjunction with Rayleigh instability and have been investigated both experimentally and numerically [28, 29].

It has been observed experimentally that nanowire junctions have a drastic effect on the break-up kinetics of Au and Ag nanowires when annealed at elevated temperatures much below their melting point [30]. Presence of such junctions between the nanowires lead to initial break-up preferentially at the junction, followed by break-up at remainder of the nanowires. Such fragmentation behaviour of nanowires can be exploited to produce ordered array of nanodots for different technological applications [31, 32].

In the past, various modelling approaches (mostly atomistic) have been adopted to simulate the nanoparticle morphologies and various effects at the nanoscale — a review of such approaches can be found in [33] and references therein. Linear stability analysis of Rayleigh instability is also well understood; for example, a linear stability analysis of the effect of general surface energy anisotropy on Rayleigh instability has been carried out in [16] (extending the work of Cahn [14]).

Phase-field modelling is an efficient numerical technique for simulating microstructural evolution at the mesoscopic length scales and diffusive time scales [34, 35]. There exist several phase-field models to study variable mobility; for example, variable mobilities have been introduced in the past to study phenomena such as domain growth in binary mixtures [36], late-stage coarsening in phase separating systems [37, 38], and for determining the coarsening kinetics of bulk-diffusion-controlled and interface-diffusion-controlled growth in systems with interconnected phases [39]. The use of variable mobility phase-field models has also been made for effectively incorporating the effect surface diffusion, assuming isotropic interfacial energy [40, 41, 42]. Such variable mobility phase-field models have been used in simulating the Rayleigh instability in the solid-state [43], destabilisation of nanoporous membranes by grain boundary grooving [44], thermal stability of nanoporous aggregates [45], and, instability in multi-layer nanocrystalline thin-films due to
Rayleigh instability driven by grain boundary [46].

Phase-field models have been developed to incorporate anisotropy in interfacial energy using either trigonometric functions for the interfacial energy coefficient [47, 48], or using higher order tensor terms which has benefits over the former approach [49]. Phase-field model for stability of nanowire fragmentation with regularized trigonometric function of interfacial energy along with finite amplitude axisymmetric perturbations has been developed previously [50]. Higher order tensor terms in the free energy functional of phase-field models have been used to study the faceting of precipitates due to interfacial energy anisotropy [51].

Our aim, in this paper, is to implement a continuum model (based on the Cahn-Hilliard equation [52]) for long time evolution of the morphologies of the nanowires with enhanced surface diffusion. Further, we want to study the systems in which the surface energy is anisotropic. Specifically, we use the extended Cahn-Hilliard equation which consists of a fourth order tensor term in order to incorporate cubic surface energy anisotropy, and, following the approach adopted in some of the previous phase-field studies mentioned above, we define an order-parameter dependent mobility function. This helps us incorporate enhanced surface diffusion in our model. Using this model, we carry out a systematic study of various factors such as wire diameters, the angles of intersection, density of intersections in the simulation cell and interfacial energy anisotropy on fragmentation of intersecting nanowires.

At this point, we want to note that there exist phase-field studies pertaining to the phenomena of solid-state dewetting in nanowires [53, 54, 17]. Different phenomena like the formation of nanoparticles through solid-state dewetting of a thin-film on a substrate [55], stress effects on solid-state dewetting of thin-films [56], solid-state dewetting of Au aggregates on titanium oxide nanorods [57], and effect of surface energy anisotropy on Rayleigh-like solid-state dewetting [17] have been studied in the past. However, unlike these models which include the substrate on which dewetting takes place, in our model, the wires are free-standing.

The rest of this paper is organized as follows: we describe (albeit briefly) the formulation and numerical implementation of the phase-field model in section 2, which also contains the simulation details. Results and discussion follow in section 3 where we discuss the effect of various parameters on the kinetics of junction break-up systematically, followed by a summary of our salient conclusions in section 4.

2. Phase-field model

As indicated in the introduction, our phase-field model is a combination of extended Cahn-Hilliard model for cubic anisotropy in interfacial energy [49] coupled with enhanced surface diffusion implemented using a variable mobility [39]. Since these models are well known in the literature, we briefly describe the models and other details in this section, for the sake of completion.

2.1. Formulation

We consider a conserved, non-dimensionalised order parameter, denoted by \( c(x,t) \) to describe our system. This order parameter takes a value of zero in vacuum and unity in the (nanowire) material albeit across a flat interface; in the circular cross-section nanowire-vacuum geometry, the order parameter value shifts from unity and zero to account for Gibbs-Thomson effect.
The free energy functional of the system is given by the expression:

\[ F = N_V \int_{\Omega} \left\{ f_0(c) + \frac{\kappa_c}{2} (|\nabla c|)^2 + \frac{\gamma_{<hkl>}}{2} (\nabla^2 c)^2 \right\} d\Omega, \tag{1} \]

where, \(N_V\) denotes the number of atoms per unit volume (assumed to be constant), \(f_0(c)\) is the bulk free energy density per atom, \(\kappa_c\) is the gradient energy coefficient (assumed to be a scalar and hence gives rise to an isotropic interfacial free energy), and, the third term accounts for cubic interfacial free energy anisotropy as explained below.

The cubic anisotropy in the interfacial energy of the nanowires is incorporated into the model using the extended Cahn-Hilliard formulation [49], which is the third term in the equation. In Eq. 1, \(\gamma_{<hkl>}\) is the coefficient of a fourth order term which is defined for a particular crystallographic orientation as:

\[ \gamma_{<hkl>} = \gamma_I + \gamma_A (h^4 + k^4 + l^4), \tag{2} \]

where, \(\gamma_A\) and \(\gamma_I\) are the anisotropic and isotropic contributions from the fourth rank term, and \(h, k, l\) denote the Miller Indices of the normal to an interface. The values of \(\gamma_A\) and \(\gamma_I\) can be calculated from the scaling curve in [49], if the ratio of interfacial energies along two directions is known.

In Eq. 1, the function \(f_0(c)\) represents the bulk free energy density per atom, which is given by the polynomial,

\[ f_0(c) = A_c \left[ c^2 (1 - c)^2 \right]. \tag{3} \]

This polynomial produces a double well potential with the energy minima at \(c=0\) (vacuum) and \(c=1\) (nanowire material). \(A_c\) is a coefficient that determines the height of the potential energy barrier. Together with the gradient energy coefficient \(\kappa_c\), \(A_c\) determines the interfacial energy and width in the system (in the absence of the \(\gamma_{<hkl>}\) term; when present, \(\gamma_{<hkl>}\) along with \(A_c\) and \(\kappa_c\) determine the interfacial properties, namely, energy and width).

The chemical potential is derived from the variational derivative of the free energy functional Eq.1:

\[ \mu = \frac{1}{N_V} \frac{\delta F}{\delta c} = \left[ \frac{\partial f_0(c)}{\partial c} - \kappa_c \nabla^2 c + \gamma_{<hkl>} \nabla^4 c \right]. \tag{4} \]

The evolution of the system is described by the modified Cahn-Hilliard equation, which is given by the expression:

\[ \frac{\partial c}{\partial t} = \nabla \cdot \left[ M(c) \cdot \nabla \left( \frac{df}{dc} - \kappa_c \nabla^2 c + \gamma_{<hkl>} \nabla^4 c \right) \right], \tag{5} \]

where, \(M(c)\) denotes the mobility as a function of the order parameter, and is used to capture the effect of surface diffusion.

Various polynomials have been suggested in the literature for use as variable mobility functions in the Cahn-Hilliard equation. Most commonly used mobility functions in previous studies have been quadratic and quartic function [58, 59, 60, 61, 62] of order parameter, to incorporate the dominating role of surface diffusion in the models. We have used a mobility function in our model which serves the same purpose, but with an added advantage of reducing the stiffness of the equations in conjunction with the semi-implicit Fourier spectral numerical method. The function is defined as:

\[ M(c) = \left[ c(1-c) \right]^{\frac{1}{2}}. \tag{6} \]
The above function gives rise to the highest mobility of atoms along the interface (c = 0.5) and defines zero mobility of atoms in the bulk (c = 1) and the mobility is restricted to the solid (that is, mobility in the vacuum c = 0 is also zero). Thus, in these simulations, surface diffusion plays a dominant role in material transport.

Substituting (6) into (5), the evolution equation can be written as:

$$\frac{\partial c}{\partial t} = \nabla \cdot \left[ \{c(1-c)\}^{\frac{3}{2}} \cdot \nabla \left( \frac{df}{dc} - \kappa c \nabla^2 c + \gamma_{<hh;} \nabla^4 c \right) \right]. \quad (7)$$

2.2. Numerical implementation

The evolution equation (Eq. 7) is solved numerically in order to track the morphological evolution of both finite and infinite cylindrical nanowires (in both 2-D and 3-D). We use the semi-implicit Fourier spectral technique for solving the evolution equation. This method is known to be efficient for solving non-linear partial differential equations and also eliminates the severe time-step constraint [39, 63]. We follow the same method of discretisation used in [39]. We transform equation (7) to Fourier space and perform first order forward finite-difference discretisation in time.

$$\frac{\tilde{c}(k,t+\Delta t) - \tilde{c}(k,t)}{\Delta t} = i k \{ \{c(1-c)\}^{\frac{3}{2}} \cdot [i k (\tilde{g}(c') + \tilde{c}(k') \chi)] \} k, \quad (8)$$

where, i is the pure imaginary number,

$$\chi = (\kappa c k^2 + \gamma_I k^4 + \gamma_A (k_x^4 + k_y^4 + k_z^4)),$$

$\tilde{c}(k,t)$ is the non-dimensionalised order parameter field in the Fourier space and, k and k' are the Fourier space vectors. |k| = k = $\sqrt{k_x^2 + k_y^2 + k_z^2}$, where k_x, k_y and k_z are the three components of the Fourier space vector. The operation { } represents the inverse spatial Fourier transform of the quantity in square brackets to the real space, while { }_r represents the forward spatial Fourier transform of the quantity in curly brackets. The function g(c) represents the derivative of the bulk free energy density function with respect to c and is defined as:

$$g(c) = \frac{\partial f_0(c)}{dc} = 2A_c \{ c(1-c)(1-2c) \}. \quad (9)$$

The severe time step constraint associated with the explicit solution of the equation is circumvented by introducing a suitable stabilizing constant, which separates the mobility function into two parts: $\xi$ and $\{c(1-c)\}^{\frac{3}{2}} - \xi$, after Zhu et al. [39]. Therefore, the modified evolution equation becomes:

$$\frac{\tilde{c}(k,t+\Delta t) - \tilde{c}(k,t)}{\Delta t} = i k \left\{ \xi + \left\{ \{c(1-c)\}^{\frac{3}{2}} - \xi \right\} \right\} \cdot [i k (\tilde{g}(c') + \tilde{c}(k') \chi)]_r \} k. \quad (10)$$

After some algebraic manipulation, the evolution equation can be written as:

$$\beta \tilde{c}(k,t+\Delta t) = \beta \tilde{c}(k,t) + i k \Delta t \{c(1-c)^{\frac{3}{2}} \cdot [i k (\tilde{g}(c') + \tilde{c}(k') \chi)]_r \} \} k \quad (11)$$

where, $\beta = (1 + \xi \Delta t \chi)$.

Thus, knowing the c at a given time t, the c at time t + \Delta t can be obtained in the Fourier space using Eq. 11.
Table 1. Non-dimensional simulation parameters

<table>
<thead>
<tr>
<th>Simulation Case</th>
<th>Simulation Parameters</th>
<th>Values</th>
</tr>
</thead>
<tbody>
<tr>
<td>General parameters</td>
<td>( \kappa_c )</td>
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</tr>
<tr>
<td></td>
<td>( A_c )</td>
<td>1.0</td>
</tr>
<tr>
<td></td>
<td>( \xi )</td>
<td>0.5</td>
</tr>
<tr>
<td>Isotropic interfacial energy case</td>
<td>( Nx \times Ny \times Nz ) (3D)</td>
<td>768 \times 768 \times 96</td>
</tr>
<tr>
<td></td>
<td>( \Delta x = \Delta y = \Delta z )</td>
<td>0.5</td>
</tr>
<tr>
<td></td>
<td>( \Delta t )</td>
<td>1.0</td>
</tr>
<tr>
<td>Anisotropic interfacial energy case</td>
<td>( \gamma_I = \gamma_A )</td>
<td>0</td>
</tr>
<tr>
<td></td>
<td>( Nx \times Ny ) (2D)</td>
<td>512 \times 512</td>
</tr>
<tr>
<td></td>
<td>( \Delta x = \Delta y )</td>
<td>1.0</td>
</tr>
<tr>
<td></td>
<td>( \Delta t )</td>
<td>0.01</td>
</tr>
<tr>
<td></td>
<td>( \gamma_I )</td>
<td>-50 [65]</td>
</tr>
<tr>
<td></td>
<td>( \gamma_A )</td>
<td>107.69 [65]</td>
</tr>
</tbody>
</table>

2.3. Simulation details

We have carried out simulations of finite and infinite nanowires in both 2- and 3-D. In this paper, we present 3-D results for wires with isotropic interfacial energy and 2-D results for wires with (cubic) anisotropic interfacial energy. Note that the employment of Fourier spectral technique for the numerical solution implies imposition of periodic boundary conditions. We introduce a small noise in the scaled order parameter, which adequately simulates the thermal noise in the system. We used the software package Fastest Fourier Transform in the West (FFTW3) [64] for computing the discrete Fourier transforms. We use the same non-dimensionalisation as described in Abinandanan and Haider [49]. The non-dimensional simulation parameters used in our simulations are tabulated in Table 1.

3. Results and discussion

The angle of intersection of the nanowires, the radii of the nanowires and the size difference in the radii between the nanowires that form the intersections, the density of intersections and the anisotropy in the surface energy of the nanowires are the parameters that are of interest to us. In this section, we present our results for all these scenarios.

3.1. Effect of relative orientation

We consider a system with isotropic interfacial energy (in 3D) with a single intersection of the nanowires (of circular cross-section) in the simulation cell. We assume periodic boundary conditions. As seen from the schematic top view of the relative orientations in Figure 1, in the case of an intersection angle of 90°, both the wires are infinite. However, for all the other three angles, the nanowire parallel to the x-axis of the simulation cell is infinite while the other one is finite. Having said that, we have chosen big enough system sizes so that the break-up at the edges of the finite nanowire does not affect the break-up at the intersection.
In Figure 2, we show the time evolution of the nanowires of equal initial radii ($R_1 = R_2 = 12$ (non-dimensional) length units) with an angle of $90^\circ$ at the intersection to begin with. Note that in 3D, one nanowire (in this case, the one along the $x$-axis) is at the bottom and the other on top (in this case, the one along the $y$-axis); in this and the subsequent cases, $R_1$ represents the radius of the nanowire at the bottom and $R_2$ represents the radius of the nanowire on top.

As can be seen from the figure, due to the high curvatures at the point of contact at the intersection, initially, a junction forms at the intersection (Figure 2(a), corresponding to a (non-dimensional) time of 1000 units). The material accumulation at the junction leads to the break-up of the nanowire (Figure 2(b), corresponding to a (non-dimensional) time of 1750 units). This, in turn, leads to subsequent break-up of the nanowire as seen in Figure 2(c)-(e), corresponding to a (non-dimensional) times of 2500, 2750 and 2800 units. As can be seen from Figure 2(f), corresponding to a (non-dimensional) time of 2900 units, the broken pieces of the nanowire coarsen due, primarily to, the difference in sizes between the central particle and the others along the wire length.

In order to better understand the effect of orientation, in Figure 3, we show the morphological evolution in the case of an angle of intersection of $45^\circ$ between the two nanowires (of the same radii, namely, 12 units). In this case also, there is junction formation at the intersection; however, unlike the previous case where the contact between the nanowires is at a point, in this case, the contact between the two wires is along a line. Hence, the differences in curvatures at different points at the intersection lead to more material filling in at the sites which make smaller angle with the wire along the $x$-axis. Thus, when the central break-up takes place, the morphology of the central particle is not spherical; it is elongated and is aligned closer to (the infinite wire along) the $x$-axis. The subsequent break-ups and the coarsening are similar to the earlier case.

In Figure 4 and Figure 5, we show the morphological evolution for the cases of nanowires (of radii 12 units) which make angles of intersection of $30^\circ$ and $60^\circ$, respectively. These morphologies are qualitatively similar to that in Figure 3 in terms of the morphology of the central particle.

These microstructural features are in good agreement with experimental observations. For example, all the features noticed in the simulations above, namely, the formation of junction, the first break-up at the junction, and elongated central particle when the angle of intersection of wires is not $90^\circ$ are seen in experiments – specifically, see the Figures 3 and 4 of [30]. Interestingly, our simulation results also resemble nano-welds generated experimentally using different techniques like furnace.
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Figure 2. Morphological evolution of two nanowires intersecting at 90° at different times. The video of the break-up is available as supplementary data.

annealing [66, Figure 3(c)], and laser nano-welding of long Ag nanowires [1, Figure 4]. However, it is not clear to us if these welding are a result of local melting at the junction. In our simulations, however, there is no local melting and all the morphological changes are through mass transport by enhanced surface diffusion.

Phase-field modelling has been used previously to simulate the sintering of Ag nanoparticles [67]. The effect of local sintering at the junction of nanowires have also been studied using atomistic simulation methods, where it was observed that the nanowires undergo self-limiting rotation during neck growth, which is a result of complex interaction of surface diffusion and dislocation growth [68]. We also observe the nanowire junction break-up in all cases described above as a result of local sintering at the junctions of nanowires. In isolated nanowires, the primary cause of fragmentation is the Rayleigh instability. But, the presence of junctions lead to modification of curvature and chemical potential in the intersection region, leading to
junction formation followed by preferential break-up at the junctions.

Our simulation results are also in good agreement not only with the experimental results but also with the kinetic Monte Carlo simulation studies of Vigonski et al [30]. They reported a similar observation of preferential fragmentation of nanowires initially at the junction. Vigonski et al, proposed that intersecting surfaces of nanowires act as sites of defects promoting atomic diffusion and attributed break-up at the junction primarily to the mechanism of diffusion of surface atoms. In this study, we show that the geometric factors in terms of the curvature leads to sintering at the junctions, of course, assisted by faster surface diffusion. Further, unlike the results from the Monte Carlo simulations, the phase-field model allow us to explore long time dynamics and morphological evolution such as the subsequent nanodot formation and the coarsening of the dots.
In order to better understand the junction formation and the subsequent break-up at the junctions, we have mapped the Gaussian curvature and chemical potential in these systems. As an example, we show the chemical potential maps at two different time steps — one at the onset of junction formation and the other after break-up — and the corresponding Gaussian curvature maps in Figure 6 for the first case, namely, when the wires are orthogonal to each other. In this plot, the Gaussian curvature is visualized as a colour map (at the order parameter isosurface of $c = 0.5$) overlaid on the nanowire assembly. The chemical potential is visualized as a colour map in a plane which cuts through the cross section of nanowires (the nanowires are superimposed for visual clarity). The colour maps for the chemical potential correspond to excess chemical potential above its mean value. Not surprisingly, the chemical potential maps have one-to-one correspondence with the Gaussian curvature maps indicating that the driving forces for atomic diffusion at different regions of the nanowire assembly are due to the surface energy. From the Gaussian curvature maps it can be seen that the two principal curvatures assume values of opposite sign giving rise to a saddle shaped geometry when the nanowires sinter at the junction. Initially, due to the high curvature at the constrictions formed near the junction (Figure 6(a)), chemical potential is substantially high in this region as can be seen in Figure 6(c), leading to higher atomic transport. Hence, atoms diffuse from these narrow regions towards the central nanoparticle and arms of the nanowires. Therefore, these constrictions get narrower finally causing detachment of nanowires from the junction.

Thereafter, the free ends of the nanowires retract due to high curvature at the tip of the broken junction. As these nanowire free ends retract, more matter accumulates
and these tips get blunted. Subsequently these tips acquire a spherical shape and get detached; this mechanism is the same as observed in Rayleigh instability driven break-up. This process continues leading to formation of further constrictions along the arms of the nanowires, which are regions of higher chemical potential as can be seen in Figure 6(d). This leads to subsequent formation of nanodots. These nanodots have a positive Gaussian curvature as can be seen in Figure 6(b), which occurs due to the spheroidisation of the nanoparticles in order to reduce the (isotropic) interfacial energy.

The angle between the nanowires does not affect the sequence of the nanowire break-up; the first fragmentation always occurs at the junction; but, it does affect the break-up kinetics. The time to first break-up (at the junction) is calculated for different orientations, and plotted in Figure 7. Here, we have assumed that there is a break-up at the junction if two or more of the arms at a junction (consisting of four arms) detach. The data points are obtained from a set of three different simulations for each configuration (that is, by using three different seed values of pseudo-random number generator). It is observed that the system is relatively more stable as the acute angle between the nanowires decrease. The time to first junction break-up is highest for the 30° configuration system, and the least for 90° configuration system, when only the effect of relative wire orientation is considered in isolation. This observation can be correlated with the average distance between nearest nanodots from the central nanoparticle along the two nanowires, formed subsequently after the junction break-up (values given in Table 2). From the values presented in Table 2, it can be inferred that the average separation between the nanodots from the central nanoparticle along
the two wires increases as the angle between the nanowires decrease. These values were calculated by averaging the results from three different set of simulations. The correlation between time to first junction break-up and average separation between the nanodots from the junction center can be explained with the Gaussian curvature maps; as the angle between the nanowire decrease, the curvature increases at the junction which leads to enhanced atomic transport in between the two wires. Therefore, more material accumulates at the central agglomerate before constriction occurs at the junction, leading to nanowire junction break-up. For this reason, the central nanoparticle acquires an oblate spheroidal shape as the the angle between nanowire is reduced. The end result is the junction break-up substantially delayed along with the particles being placed afar from the center of the junction.

### 3.2. Effect of relative wire diameter

It has been observed experimentally that there is on average about 25% variation in the diameter of the fabricated metallic nanowires [20]. Therefore, in order to study the effect of relative variation in diameters of the nanowires, we use three different assemblies of nanowires in 90° configuration, with initial radii of $R_1, R_2 = 12, 14, 16$. We study the three different combinations of radii—the first combination with $R_1 = 14, R_2 = 16$, the second combination with $R_1 = 12, R_2 = 14$, and the final

<table>
<thead>
<tr>
<th>Wire configuration</th>
<th>Distance along wire 1</th>
<th>Distance along wire 2</th>
</tr>
</thead>
<tbody>
<tr>
<td>30° configuration</td>
<td>110.9 ± 0.4</td>
<td>111.5 ± 0.8</td>
</tr>
<tr>
<td>45° configuration</td>
<td>94.1 ± 0.9</td>
<td>93.9 ± 0.6</td>
</tr>
<tr>
<td>60° configuration</td>
<td>87 ± 0</td>
<td>85.3 ± 1.4</td>
</tr>
<tr>
<td>90° configuration</td>
<td>83 ± 0</td>
<td>83 ± 0</td>
</tr>
</tbody>
</table>

Table 2. Distance of first nanodots from the central nanoparticle (wire 1 corresponds to the infinite length nanowire at the bottom, and wire 2 corresponds to the finite length inclined nanowire on top of the infinite length nanowire).
Figure 7. Plot showing the dependence of time to first break-up at the junction on the relative wire orientation. The line connecting the data points is drawn only as a guide to the eye.

<table>
<thead>
<tr>
<th>Wire configuration</th>
<th>Time to first junction break-up</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_1 = 12, R_2 = 12$</td>
<td>$1706 \pm 12$</td>
</tr>
<tr>
<td>$R_1 = 12, R_2 = 14$</td>
<td>$1623 \pm 12$</td>
</tr>
<tr>
<td>$R_1 = 12, R_2 = 16$</td>
<td>$1622 \pm 10$</td>
</tr>
<tr>
<td>$R_1 = 14, R_2 = 14$</td>
<td>$4000 \pm 5$</td>
</tr>
<tr>
<td>$R_1 = 14, R_2 = 16$</td>
<td>$3907 \pm 15$</td>
</tr>
<tr>
<td>$R_1 = 16, R_2 = 16$</td>
<td>$8142 \pm 14$</td>
</tr>
<tr>
<td>4-junction ($R_1 = 12, R_2 = 12$)</td>
<td>$1694 \pm 9$</td>
</tr>
<tr>
<td>9-junction ($R_1 = 12, R_2 = 12$)</td>
<td>$1691 \pm 6$</td>
</tr>
</tbody>
</table>

Table 3. Time units to first break-up at the junctions for different configurations.

Combination with $R_1 = 12, R_2 = 16$; with the relative radius variations of 14%, 17%, and 33%, respectively. We have carried out a set of three different simulations for each case, and the average from these simulations are presented here.

It is observed that for all three combinations, the nanowires with smaller radius breaks up at the junction and the central agglomerate becomes part of the larger radius nanowires. The time to first junction break-up (values given in Table 3) within a given margin of error is dependent primarily on the radius of the smaller diameter nanowire. Having said that, the difference in the radii of the nanowires has a small but definite effect on kinetics. The kinetics when the radii are different is slightly faster than when the radii are the same; for example, for the cases of $R_1 = 12, R_2 = 14$ and $R_1 = 12, R_2 = 16$ are slightly faster than $R_1 = R_2 = 12$ case.

We have summarised in Figure 8 the data given in Table 3. We have used the $90^\circ$
configuration for $R_1, R_2 = 14$ and $R_1, R_2 = 16$ and compare it with the $90^\circ$ case with $R_1, R_2 = 12$. From Figure 8, it can be observed that the time to first junction break-up increases drastically as the radius of the nanowires is increased. This difference, in our opinion, is related to the reduction in driving force due to increasing size of the nanowires which leads to smaller driving forces and the fact that in our simulations while the radii are increased, the inter-junction distance is maintained a constant.

### 3.3. Effect of the density of junctions

During fabrication of nanowires, it is seldom possible to fabricate a nanowire in isolation. In most practical cases, they are fabricated in large numbers with the nanowire network resembling structures best approximated as a grid pattern [69]. It has been observed that local sintering at the junction of nanowires has drastic effects on the optimization of electrical and optical properties of the nanowire networks [7, 66, 10, 70]. The network density (no of junctions in close proximity) also plays a role in optical transmittance of the assembly. Therefore, we have have carried out systematic study of nanowire assemblies consisting of grids with 1, 4, and 9 junctions in the simulation cell. Since the 4 and 9-junctions behave qualitatively the same, we only show the results for the 9-junction configuration in Figure 9. In all the three cases, we observe the first fragmentation of the nanowires to occur at the junctions; however, the specific junction at which the first detachment occurs is stochastic in nature. We track the time to first junction break-up for all the three
cases, and correlate the junction break-up kinetics with the number of junctions in close proximity, the values of which are given in Table 3. It is observed that within the given margin of error, there is no substantial difference between the time to first junction break-up. Therefore, close proximity of the junctions does not affect the the break-up kinetics of individual junctions in the network. The kinetics remains unaffected, but the morphological evolution plays a role in the network electrical resistance which falls during annealing to reach a stable minima followed by an abrupt rise, as reported in [7, 10]. This experimental observation can be directly correlated with the morphological evolution of the nanowire assembly of the 9-junction grid as seen in Figure 9(a) to (d). As the sintering occurs, the network resistance is expected to decrease continuously due to junction formation, followed by an abrupt increase due to fragmentation at the junctions.

3.4. Effect of interfacial energy anisotropy

Experimentally, it is known that single-crystalline and poly-crystalline metallic nanowires possess faceted morphologies and this preference in surface orientation is attributed to surface energy anisotropy [21]. The diverse effects of surface energy anisotropy in FCC metallic nanowires have been investigated using Monte Carlo models [18]. It has been reported that Au nanowires develop facets as a result surface diffusion in order to minimize the surface energy [30].

Therefore, in this section we present 2D simulation results on the effect of
anisotropy in surface energy of the nanowires on morphological change and junction break-up. Note that 3D simulations are also possible; however, given the highly non-linear nature of the evolution equations, and the variable mobility (to account for the faster surface diffusion), the time steps are extremely small and hence the system has to be evolved to much higher time steps to observe break-up. Hence, at the moment, we are not able to carry out 3D simulations in reasonable amounts of time. However, efforts of parallel implementation of these models are in progress in our group; such implementations, when available, will help us study 3-D anisotropic systems.

We study two different configurations with nanowires oriented at an angle of 90° and 45°. In this case, we use the wire radius of value $R_1, R_2 = 6$. The values of the isotropic and anisotropic contributions to the gradient energy coefficient, namely $\gamma_I$ and $\gamma_A$ are given in Table 1. The values are chosen such that the $<11>$ direction is energetically more favoured than the $<10>$ direction, i.e., the ratio of the interfacial energies (anisotropy ratio) $R_{\sigma} = \sigma_{<11>} / \sigma_{<10>}$ is chosen to be less than unity. Hence, it is expected that the morphological evolution of the nanowires will lead to surfaces on the nanowires whose surface normal vectors are along the energetically favoured $<11>$ direction. As noted above, the $\Delta t$ values are to be chosen appropriately in this case in order to maintain the stability of the stiff numerical scheme.

The 2D microstructure maps for the 90° case is given in Figure 10, and the maps for the 45° are given in Figure 11. From the microstructure maps, it is evident that for the 45° case, the wire aligned along the energetically favoured direction is stabilized, whereas the wire aligned along the less energetically favoured direction undergoes change in morphology. The morphological change in the 90° case is such that constrictions develop at regular intervals so as to give rise to surfaces with the surface normal vectors aligned parallel to the $<11>$ direction. In both the cases, we observe that the fragmentation of the nanowires occurs initially at the junction, followed by break-up along the nanowire arms. This observation leads to the conclusion that the order in which the nanowires fragment is independent of the anisotropy in interfacial energy, with the first break-up occurring at the junction. After the fragmentation the nanowires retract, and it is expected that in case of 90° configuration, further fragmentation will occur along the nanowire arms. Further, in spite of the overall higher interfacial energy in the anisotropic cases, note that the kinetics of break-up is, relatively speaking, slower. This is primarily due to the stabilization of certain interfaces, we believe.

In the past, theoretical treatment of surface energy anisotropy [14, 50] predicted that the weak axisymmetric perturbations will be stabilized depending on the nature of derivatives of interfacial energy (particularly the second derivative). Our phase field results above can be thought of as a validation of these predictions and an attempt to correlate the stability criteria with the underlying crystallographic symmetry. Here again, our simulation results are in good agreement with the kinetic Monte Carlo simulation results obtained by Vigonski et al. [30], where they aligned the Au nanowires along $<110>$ direction and observed the fragmentation to occur initially at the junction. In their simulation, the nanowires initially having $\{110\}$ facets decomposed to more stable $\{111\}$ and $\{100\}$ facts. Our phase-field simulation results also reproduce same results; the nanowires develop energetically stable facets before undergoing fragmentation.
Phase-field study of surface diffusion enhanced break-ups of nanowire junctions

Figure 10. Morphological evolution of two nanowires with cubic anisotropic interfacial free energy, and, intersecting at 90° at different times. The $<11>$ interfaces are preferred over $<10>$ interfaces.

Figure 11. Morphological evolution of two nanowires with cubic anisotropic interfacial free energy, and, intersecting at 45° at different times. The $<11>$ interfaces are preferred over $<10>$ interfaces.

4. Summary and conclusions

In this paper, we have shown, using a phase field model (implemented in both 2- and 3-D), that at the intersection of nanowires, sintering (curvature driven material flow) leads to the formation of junctions. These junctions act the initiators of nanowire break-up; the subsequent break-ups take place due to Rayleigh instability at the arms away from these junctions. The fragments coarsen due to the differences in sizes. Further, the effect of various parameters on the junction break-up can be summarised as follows:

- The radii of the nanowires play a key role in the kinetics; smaller the radii, faster is the kinetics. The kinetics is determined primarily by the radius of the smaller of the two nanowires that intersect.
- The angle of intersection is the next key parameter; smaller the angle of intersection, slower the break-up at the junction. This is primarily due to the non-spherical morphology (and, relatively larger size) of the junction.
- The above two observations in terms of the size difference and the effect of intersection angle can be rationalised in terms of the Gaussian curvatures (and, hence chemical potential) maps.
The density of intersections in the simulation cell have very little or no effect on the kinetics.

In the case of systems with surface energy anisotropy, wires with surfaces along the energetically favourable directions are unconditionally stable. Further, the anisotropy in surface energy has a strong effect on kinetics; however, the overall morphological evolution is qualitatively the same – namely, junctions form, and the first break-up takes place at the junctions.

Thus, phase-field models, and the simulation results based on them could be of use and importance in the study of stability of nanowire nets and their morphological evolution at long time scales.

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Supplementary data

The videos of fragmentation of nanowire intersections under different simulation conditions are available for download at the following link:

https://data.mendeley.com/datasets/vjtvmvxfhx/1

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